



DMG3415U

Product Summary

V _{(BR)DSS}	R _{DS(on) max}	Ι _D T _A = +25°C
201/	$42.5m\Omega @ V_{GS} = -4.5V$	-4.0A
-20V	71mΩ @ V _{GS} = -1.8V	-2.0A

Description

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- DC-DC Converters
- Power Management Functions

Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Up To 3kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

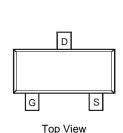
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
- Solderable per MIL-STD-202, Method 208 (3)
- Terminals Connections: See Diagram Below
- Weight: 0.008 grams (Approximate)



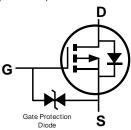


Top View

SOT23



Internal Schematic



Equivalent Circuit

Ordering Information (Note 4)

Part Number	Compliance	Case	Packaging
DMG3415U-7	Standard	SOT23	3,000/Tape & Reel
DMG3415UQ-7	Automotive	SOT23	3,000/Tape & Reel
DMG3415U-13	Standard	SOT23	10,000/Tape & Reel

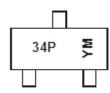
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



34P = Product Type Marking Code $YM or <math>\overline{YM}$ = Date Code Marking for Y or \overline{Y} = Year (ex: A = 2013) M = Month (ex: 9 = September)

Date Code Key

Date Odde Rey												
Year	200	9	2010		2011	20	12	2013		2014	2	2015
Code	W		Х		Y	2	<u>Z</u>	А		В		С
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Drain-Source Voltage	V _{DSS}	-20	V
Gate-Source Voltage	V _{GSS}	±8	V
Continuous Drain Current (Note 5) $V_{GS} = -4.5V$	ID	-4.0 -3.5	A
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I _{DM}	-30	A

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 5)	PD	0.9	W
Thermal Resistance, Junction to Ambient (Note 5)	R _{θJA}	139	°C/W
Thermal Resistance, Junction to case (Note 5)	R _{θJC}	32	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 6)						
Drain-Source Breakdown Voltage	BV _{DSS}	-20	—	_	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current	IDSS	_	—	-1	μA	$V_{DS} = -20V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	—	—	±10	μA	$V_{GS} = \pm 8.0 V$, $V_{DS} = 0 V$
ON CHARACTERISTICS (Note 6)			•			
Gate Threshold Voltage	V _{GS(th)}	-0.3	-0.55	-1.0	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$
		-	31	42.5		$V_{GS} = -4.5V, I_D = -4.0A$
Static Drain-Source On-Resistance	R _{DS(ON)}	-	40	53	mΩ	V _{GS} = -2.5V, I _D = -3.5A
		_	51	71		V _{GS} = -1.8V, I _D = -2.0A
Forward Transfer Admittance	g _{FS}		3	_	S	$V_{DS} = -5V, I_D = -4A$
DYNAMIC CHARACTERISTICS (Note 7)						
Input Capacitance	Ciss		294	_	pF	
Output Capacitance	Coss		104	-	pF	V _{DS} = -10V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	Crss		25	_	pF	
Gate Resistnace	Rg		250	-	Ω	$V_{DS} = 0V$, $VGS = 0V$, $f = 1.0MHz$
SWITCHING CHARACTERISTICS (Note 7)						
Total Gate Charge	Qg		9.1	_	nC	
Gate-Source Charge	Q _{gs}		1.5	_	nC	V _{GS} = -4.5V, V _{DS} = -10V I _D = -4A
Gate-Drain Charge	Q _{gd}	-	1.7	_	nC	
Turn-On Delay Time	t _{D(on)}	_	71	_	ns	
Turn-On Rise Time	tr	—	117	_	ns	V _{DS} = -10V, V _{GS} = -4.5V,
Turn-Off Delay Time	t _{D(off)}	—	795		ns	R _D = 2.5Ω, R _G = 3.0Ω, I _D = -1A
Turn-Off Fall Time	t _f	_	393		ns	

Notes: 5. Device mounted on FR-4 substrate PC board, with minimum recommended pad layout.

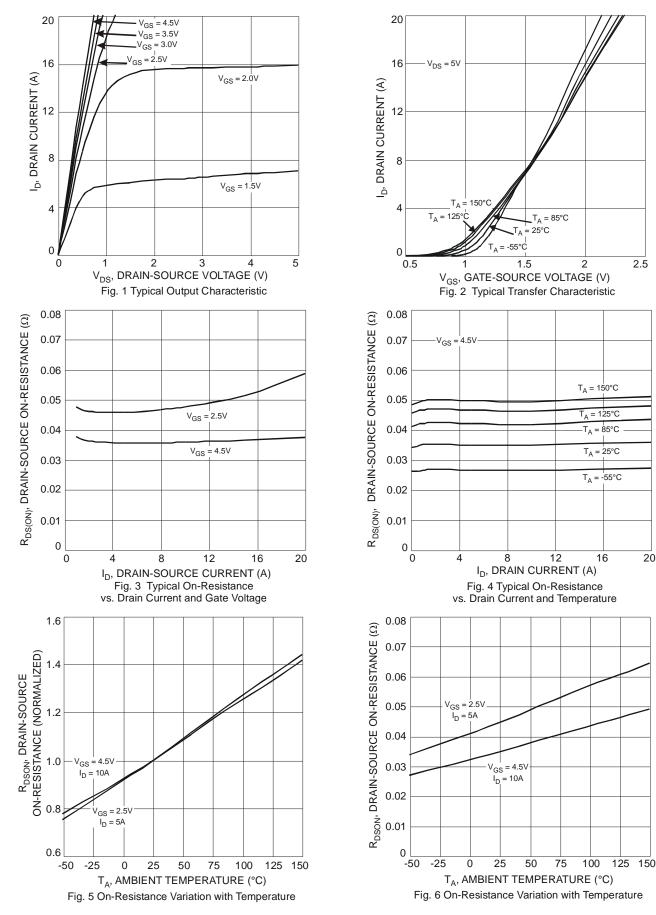
Bevice incurred of the substrate to board, with minimum t
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to production testing.



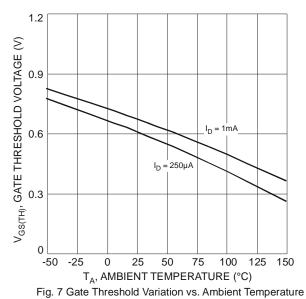
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2.5

20







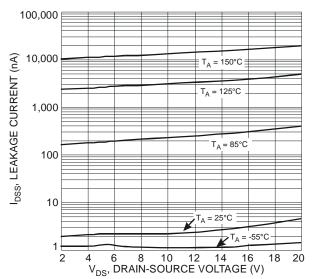
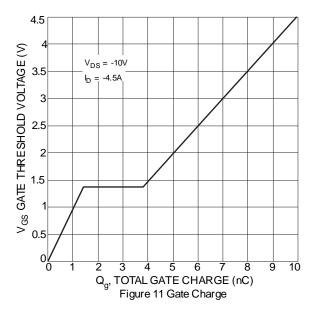
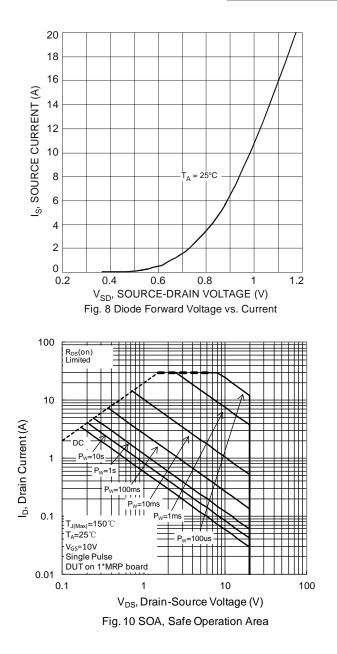
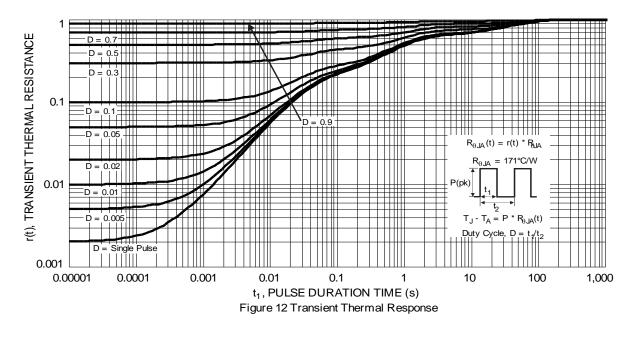


Fig. 9 Typical Leakage Current vs. Drain-Source Voltage



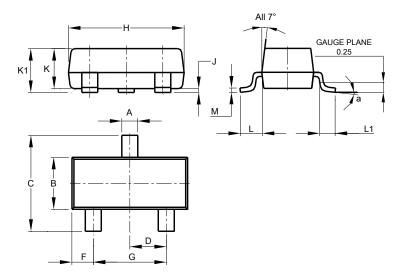






Package Outline Dimensions

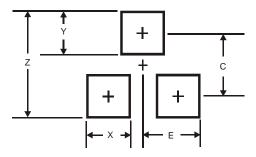
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SOT23								
Dim	Min Max Typ								
Α	0.37	0.51	0.40						
В	1.20	1.40	1.30						
С	2.30	2.50	2.40						
D	0.89	1.03	0.915						
F	0.45	0.60	0.535						
G	1.78 2.05 1.83								
н	2.80	3.00	2.90						
J	0.013	0.05							
K	0.890 1.00 0.97								
K1	0.903	1.10	1.025						
L	0.45	0.61	0.55						
L1	0.25	0.55	0.40						
М	0.085	0.150	0.110						
а	a 8°								
All	All Dimensions in mm								

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Х	0.8
Y	0.9
С	2.0
E	1.35



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